600 V driver IC for HF fluorescent lamps
Rev. 02 - 12 September 2005
Product data sheet

## 1. General description

The IC is a monolithic integrated circuit for driving electronically ballasted fluorescent lamps, with mains voltages up to 277 V (RMS) (nominal value).

The circuit is made in a 650 V Bipolar CMOS DMOS (BCD) power-logic process. It provides the drive function for the two discrete power MOSFETs.

Besides the drive function, the IC also includes the level-shift circuit, the oscillator function, a lamp voltage monitor, a current control function, a timer function and protections.

## 2. Features

- Adjustable preheat time
- Adjustable preheat current
- Current controlled operating
- Single ignition attempt
- Adaptive non-overlap time control
- Integrated high-voltage level-shift function
- Power-down function
- Protection against lamp failures or lamp removal
- Capacitive mode protection

3. Applications

- The circuit topology enables a broad range of ballast applications at different mains voltages for driving lamp types from T8, T5, PLC, T10, T12, PLL and PLT, for example.


## 4. Quick reference data

Table 1: Quick reference data
$V_{D D}=13 \mathrm{~V} ; V_{F V D D}-V_{S H}=13 \mathrm{~V} ; T_{\text {amb }}=25^{\circ} \mathrm{C}$; all voltages are referenced to GND; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Start-up state |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{DD} \text { (start) }}$ | oscillator start supply voltage |  | 12.4 | 13.0 | 13.6 | V |
| $V_{\text {DD(stop) }}$ | oscillator stop supply voltage |  | 8.6 | 9.1 | 9.6 | V |
| IDD (start) | oscillator start-up supply current | $\mathrm{V}_{\mathrm{DD}}<\mathrm{V}_{\mathrm{DD} \text { (start) }}$ | - | 170 | 200 | $\mu \mathrm{A}$ |
| High-voltage supply |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{HS}}$ | high-side supply voltage | $\mathrm{I}_{\mathrm{HS}}<30 \mu \mathrm{~A} ; \mathrm{t}<1 \mathrm{~s}$ | - | - | 600 | V |
| Reference voltage |  |  |  |  |  |  |
| $\mathrm{V}_{\text {VREF }}$ | reference voltage | $\mathrm{I}_{\mathrm{L}}=10 \mu \mathrm{~A}$ | 2.86 | 2.95 | 3.04 | V |
| Voltage controlled oscillator |  |  |  |  |  |  |
| $\mathrm{f}_{\max }$ | maximum bridge frequency |  | 90 | 100 | 110 | kHz |
| $\mathrm{f}_{\text {min }}$ | minimum bridge frequency |  | 38.9 | 40.5 | 42.1 | kHz |
| High-side output driver |  |  |  |  |  |  |
| $\mathrm{l}_{\text {(source) }}$ | output source current | $\mathrm{V}_{\mathrm{GH}}-\mathrm{V}_{\text {SH }}=0 \mathrm{~V}$ | 135 | 180 | 235 | mA |
| $\mathrm{I}_{0(\text { (sink })}$ | output sink current | $\mathrm{V}_{\mathrm{GH}}-\mathrm{V}_{\mathrm{SH}}=13 \mathrm{~V}$ | 265 | 330 | 415 | mA |
| Preheat current sensor |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{ph}}$ | preheat voltage |  | 0.57 | 0.60 | 0.63 | V |
| Lamp voltage sensor |  |  |  |  |  |  |
| $\mathrm{V}_{\text {lamp(fail) }}$ | lamp fail voltage |  | 0.77 | 0.81 | 0.85 | V |
| $\mathrm{V}_{\text {lamp(max) }}$ | maximum lamp voltage |  | 1.44 | 1.49 | 1.54 | V |
| Average current sensor |  |  |  |  |  |  |
| $\mathrm{V}_{\text {offset }}$ | offset voltage | $\mathrm{V}_{\mathrm{CS}}=0 \mathrm{~V}$ to 2.5 V | -2 | 0 | +2 | mV |
| $\mathrm{gm}_{\mathrm{m}}$ | transconductance | $\mathrm{f}=1 \mathrm{kHz}$ | 1900 | 3800 | 5700 | $\mu \mathrm{A} / \mathrm{mV}$ |
| Preheat timer |  |  |  |  |  |  |
| $t_{\text {ph }}$ | preheat time | $\begin{aligned} & \mathrm{C}_{\mathrm{CT}}=330 \mathrm{nF} ; \\ & \mathrm{R}_{\mathrm{IREF}}=33 \mathrm{k} \Omega \end{aligned}$ | 1.6 | 1.8 | 2.0 | s |
| $\mathrm{V}_{\text {OL }}$ | LOW-level output voltage |  | - | 1.4 | - | V |
| $\mathrm{V}_{\mathrm{OH}}$ | HIGH-level output voltage |  | - | 3.6 | - | V |

## 5. Ordering information

Table 2: Ordering information

| Type number | Package |  |  |  |
| :--- | :--- | :--- | :--- | :--- |
|  | Name | Description | Version |  |
| UBA2014T | SO16 | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 |  |
| UBA2014P | DIP16 | plastic dual in-line package; 16 leads ( 300 mm ); long body | SOT38-1 |  |



Fig 1. Block diagram

## 7. Pinning information

### 7.1 Pinning



Fig 2. Pin configuration (SO16)


Fig 3. Pin configuration (DIP16)

### 7.2 Pin description

Table 3: Pin description

| Symbol | Pin | Description |
| :--- | :--- | :--- |
| CT | 1 | preheat timer output |
| CSW | 2 | input of voltage controlled oscillator |
| CF | 3 | voltage controlled oscillator output |
| IREF | 4 | internal reference current input |
| GND | 5 | ground |
| GL | 6 | gate output for the low-side switch |
| $V_{\text {DD }}$ | 7 | low-voltage supply |
| PCS | 8 | preheat current sensor input |
| FV | 9 | floating supply voltage; supply for high-side switch |
| GH | 10 | gate output for the high-side switch |
| SH | 11 | source for the high-side switch |
| ACM | 12 | capacitive mode input |
| LVS | 13 | lamp voltage sensor input |
| VREF | 14 | reference voltage output |
| CSP | 15 | positive input for the average current sensor |
| CSN | 16 | negative input for the average current sensor |

## 8. Functional description

### 8.1 Start-up state

Initial start-up can be achieved by charging the low-voltage supply capacitor C7 (see Figure 8) via an external start-up resistor. Start-up of the circuit is achieved under the condition that both half-bridge transistors TR1 and TR2 are non-conductive. The circuit will be reset in the start-up state. If the low-voltage supply ( $V_{D D}$ ) reaches the value of $V_{D D(s t a r t)}$ the circuit will start oscillating. A DC reset circuit is incorporated in the High-Side (HS) driver. Below the lock-out voltage at the $F V_{D D}$ pin the output voltage $\left(\mathrm{V}_{G H}-\mathrm{V}_{\mathrm{SH}}\right)$ is zero. The voltages at pins CF and CT are zero during the start-up state.

### 8.2 Oscillation

The internal oscillator is a Voltage Controlled Oscillator (VCO) circuit which generates a sawtooth waveform between the $\mathrm{V}_{\mathrm{CF}(\text { high })}$ level and 0 V . The frequency of the sawtooth is determined by capacitor $\mathrm{C}_{\mathrm{CF}}$, resistor $\mathrm{R}_{\text {IREF }}$, and the voltage at pin CSW. The minimum and maximum switching frequencies are determined by $R_{\text {IREF }}$ and $C_{C F}$; their ratio is internally fixed. The sawtooth frequency is twice the half-bridge frequency. The UBA2014 brings the transistors TR1 and TR2 into conduction alternately with a duty cycle of approximately $50 \%$. An overview of the oscillator signal and driver signals is illustrated in Figure 4. The oscillator starts oscillating at $f_{\text {max. }}$. During the first switching cycle the Low-Side (LS) transistor is switched on. The first conducting time is made extra long to enable the bootstrap capacitor to charge.

### 8.3 Adaptive non-overlap

The non-overlap time is realized with an adaptive non-overlap circuit (ANT). By using an adaptive non-overlap circuit, the application can determine the duration of the non-overlap time and make it optimum for each frequency; see Figure 4. The non-overlap time is determined by the slope of the half-bridge voltage, and is detected by the signal across resistor R16 which is connected directly to pin ACM. The minimum non-overlap time is internally fixed. The maximum non-overlap time is internally fixed at approximately 25 \% of the bridge period time. An internal filter of 30 ns is included at the ACM pin to increase the noise immunity.

### 8.4 Timing circuit

A timing circuit is included to determine the preheat time and the ignition time. The circuit consists of a clock generator and a counter.

The preheat time is defined by $\mathrm{C}_{\mathrm{CT}}$ and $\mathrm{R}_{\text {IREF }}$ and consists of 7 pulses at $\mathrm{C}_{\mathrm{CT}}$; the maximum ignition time is 1 pulse at $\mathrm{C}_{\mathrm{C}}$. The timing circuit starts operating after the start-up state, as soon as the low supply voltage ( $\mathrm{V}_{\mathrm{DD}}$ ) has reached $\mathrm{V}_{\mathrm{DD} \text { (start) }}$ or when a critical value of the lamp voltage ( $\mathrm{V}_{\text {lamp(fail) }}$ ) is exceeded. When the timer is not operating $\mathrm{C}_{\mathrm{CT}}$ is discharged to 0 V at 1 mA .

### 8.5 Preheat state

After starting at $f_{\text {max }}$, the frequency decreases until the momentary value of the voltage across sense resistor R14 reaches the internally fixed preheat voltage level (pin PCS). At crossing the preheat voltage level, the output current of the Preheat Current Sensor (PCS) circuit discharges the capacitor $\mathrm{C}_{\mathrm{CSW}}$, thus raising the frequency. The preheat time begins at the moment that the circuit starts oscillating. During the preheat time the Average Current Sensor (ACS) circuit is disabled. An internal filter of 30 ns is included at pin PCS to increase the noise immunity.

### 8.6 Ignition state

After the preheat time the ignition state is entered and the frequency will sweep down due to charging of the capacitor at pin CSW with an internally fixed current; see Figure 5. During this continuous decrease in frequency, the circuit approaches the resonant frequency of the load. This will cause a high voltage across the load, which normally ignites the lamp. The ignition voltage of a lamp is designed above the $\mathrm{V}_{\text {lamp(fail) }}$ level. If the lamp voltage exceeds the $\mathrm{V}_{\text {lamp(fail) }}$ level the ignition timer is started.

### 8.7 Burn state

If the lamp voltage does not exceed the $\mathrm{V}_{\text {lamp(max) }}$ level the voltage at pin CSW will continue to increase until the clamp level at pin CSW is reached; see Figure 5. As a consequence the frequency will decrease until the minimum frequency is reached.

When the frequency reaches its minimum level it is assumed that the lamp has ignited and the circuit will enter the burn state. The Average Current Sensor (ACS) circuit will be enabled. As soon as the averaged voltage across sense resistor R14, measured at pin CSN, reaches the reference level at pin CSP, the average current sensor circuit will take over the control of the lamp current. The average current through R14 is transferred to a voltage at the voltage controlled oscillator and regulates the frequency and, as a result, the lamp current.

### 8.8 Lamp failure mode

### 8.8.1 During ignition state

If the lamp does not ignite, the voltage level increases. When the lamp voltage exceeds the $\mathrm{V}_{\text {lamp(max) }}$ level, the voltage will be regulated at the $\mathrm{V}_{\text {lamp(max) }}$ level; see Figure 6. When the $\mathrm{V}_{\text {lamp(fail) }}$ level is crossed the ignition timer has already started. If the voltage at pin LVS is above the $\mathrm{V}_{\text {lamp(fail) }}$ level at the end of the ignition time the circuit stops oscillating and is forced into the Power-down mode. The circuit will be reset only when the supply voltage is powered down.

### 8.8.2 During burn state

If the lamp fails during normal operation, the voltage across the lamp will increase and the lamp voltage will exceed the $\mathrm{V}_{\text {lamp(fail) }}$ level; see Figure 7. At that moment the ignition timer is started. If the lamp voltage increases further it will reach the $\mathrm{V}_{\text {lamp(max) }}$ level. This forces the circuit to re-enter the ignition state and results in an attempt to re-ignite the lamp. If during restart the lamp still fails, the voltage remains high until the end of the ignition time. At the end of the ignition time the circuit stops oscillating and the circuit will enter the Power-down mode.

### 8.9 Power-down mode

The Power-down mode will be entered if, at the end of the ignition time, the voltage at pin LVS is above $\mathrm{V}_{\text {lamp(fail). }}$. In the Power-down mode the oscillator will be stopped and both TR1 and TR2 will be non-conductive. The $V_{D D}$ supply is internally clamped. The circuit is released from the Power-down mode by lowering the low-voltage supply below $\mathrm{V}_{\mathrm{DD} \text { (reset) }}$.

### 8.10 Capacitive mode protection

The signal across R16 also gives information about the switching behavior of the half bridge. If, after the preheat state, the voltage across the ACM resistor (R16) does not exceed the $\mathrm{V}_{\mathrm{CMD}}$ level during the non-overlap time, the Capacitive Mode Detection circuit (CMD) assumes that the circuit is in the capacitive mode of operation. As a consequence the frequency will directly be increased to $f_{\max }$. The frequency behavior is decoupled from the voltage at pin CSW until $\mathrm{C}_{\mathrm{CSW}}$ has been discharged to zero.

### 8.11 Charge coupling

Due to parasitic capacitive coupling to the high voltage circuitry all pins are burdened with a repetitive charge injection. Given the typical application the pins IREF and CF are sensitive to this charge injection. For charge coupling of approximately 8 pC , a safe functional operation of the IC is guaranteed, independent of the current level.

Charge coupling at current levels below $50 \mu \mathrm{~A}$ will not interfere with the accuracy of the $\mathrm{V}_{\mathrm{CS}}$, $\mathrm{V}_{\mathrm{PCS}}$ and $\mathrm{V}_{\mathrm{ACM}}$ levels.

Charge coupling at current levels below $20 \mu \mathrm{~A}$ will not interfere with the accuracy of any parameter.

### 8.12 Design equations

The following design equations are used to calculate the desired preheat time, the maximum ignition time, and the minimum and the maximum switching frequency.
$t_{p h}=1.8 \times \frac{C_{C T}}{330 \times 10^{-9}} \times \frac{R_{\text {IREF }}}{33 \times 10^{3}}$
$t_{i g n}=0.26 \times \frac{C_{C T}}{330 \times 10^{-9}} \times \frac{R_{\text {IREF }}}{33 \times 10^{3}}$
$f_{\text {min }}=40.5 \times 10^{3} \times \frac{100 \times 10^{-12}}{C_{C F}} \times \frac{33 \times 10^{3}}{R_{\text {IREF }}}$
$f_{\text {max }}=2.5 \times f_{\text {min }}$
Start of ignition is defined as the moment at which the measured lamp voltage crosses the $\mathrm{V}_{\text {lamp(fail) }}$ level; see Section 8.8.


Fig 4. Oscillator and driver signals


Fig 5. Normal ignition behavior


Fig 6. Failure mode during ignition


Fig 7. Failure mode during burn

## 9. Limiting values

Table 4: Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages referenced to GND.

| Symbol | Parameter | Conditions | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{HS}}$ | high-side supply voltage | $\mathrm{I}_{\mathrm{HS}}<30 \mu \mathrm{~A} ; \mathrm{t}<1 \mathrm{~s}$ | - | 600 | V |
|  |  | $\mathrm{I}_{\mathrm{HS}}<30 \mu \mathrm{~A}$ | - | 510 | V |
| $V_{\text {DD }}$ | voltage at pin $\mathrm{V}_{\mathrm{DD}}$ |  | - | 14 | V |
| $\mathrm{V}_{\text {ACM }}$ | voltage at pin ACM |  | -5 | +5 | V |
| $V_{\text {PCS }}$ | voltage at pin PCS |  | -5 | +5 | V |
| VLVS | voltage at pin LVS |  | 0 | 5 | V |
| $\mathrm{V}_{\text {CSP }}$ | voltage at pin CSP |  | 0 | 5 | V |
| $\mathrm{V}_{\text {CSN }}$ | voltage at pin CSN |  | -0.3 | +5 | V |
| $\mathrm{V}_{\text {CSW }}$ | voltage at pin CSW |  | 0 | 5 | V |
| $\mathrm{T}_{\text {amb }}$ | ambient temperature |  | -25 | +80 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | junction temperature |  | -25 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\text {esd }}$ | electrostatic discharge voltage |  |  |  |  |
|  | pins $\mathrm{FV}_{\text {DD }}, \mathrm{GH}$ and SH |  | [1] -1000 | +1000 | V |
|  | pins CT, CSW, CF, IREF, GL, $\mathrm{V}_{\mathrm{DD}}$, PCS, CSN, CSP, VREF, LVS and ACM |  | [1] -2500 | +2500 | V |

[1] In accordance with the human body model, i.e. equivalent to discharging a 100 pF capacitor through a $1.5 \mathrm{k} \Omega$ series resistor.

## 10. Thermal characteristics

Table 5: Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {th( }}^{\text {(-a) }}$ | thermal resistance from junction to ambient | in free air |  |  |
|  | SO16 |  | 100 | K/W |
|  | DIP16 |  | 60 | K/W |
| $\mathrm{R}_{\text {th(j-pin) }}$ | thermal resistance from junction to pin | in free air |  |  |
|  | SO16 |  | 50 | K/W |
|  | DIP16 |  | 30 | K/W |

## 11. Characteristics

Table 6: Characteristics
$V_{D D}=13 \mathrm{~V} ; V_{F V D D}-V_{S H}=13 \mathrm{~V} ; T_{\text {amb }}=25^{\circ} \mathrm{C}$; all voltages referenced to $G N D$; see test circuit of Figure 8; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Start-up state: pin $\mathrm{V}_{\mathrm{DD}}$ |  |  |  |  |  |  |
| $V_{D D}$ | supply voltage for defined driver output | TR1 = off; TR2 = off | - | - | 6 | V |
| $\mathrm{V}_{\mathrm{DD} \text { (reset) }}$ | reset supply voltage | TR1 = off; TR2 = off | 4.5 | 5.5 | 7.0 | V |
| $\mathrm{V}_{\mathrm{DD} \text { (stop) }}$ | oscillator stop supply voltage |  | 8.6 | 9.1 | 9.6 | V |
| $\mathrm{V}_{\mathrm{DD} \text { (start) }}$ | oscillator start supply voltage |  | 12.4 | 13.0 | 13.6 | V |
| $V_{\text {DD(hys) }}$ | start-stop hysteresis supply voltage |  | 3.5 | 3.9 | 4.4 | V |
| $\mathrm{V}_{\mathrm{DD} \text { (clamp) }}$ | clamp supply voltage | Power-down mode | 10 | 11 | 12 | V |
| $\mathrm{I}_{\mathrm{DD} \text { (start) }}$ | start-up supply current | $\mathrm{V}_{\mathrm{DD}}<\mathrm{V}_{\mathrm{DD} \text { (start) }}$ | - | 170 | 200 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{DD} \text { (pd) }}$ | power-down supply current | $V_{D D}=9 \mathrm{~V}$ | - | 170 | 200 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{DD}}$ | operating supply current | $\mathrm{f}_{\text {bridge }}=40 \mathrm{kHz}$ without gate drive | - | 1.5 | 2.2 | mA |
| High-voltage supply: pins GH, SH and FV ${ }_{\text {DD }}$ |  |  |  |  |  |  |
| L | leakage current | 600 V at high-voltage pins | - | - | 30 | $\mu \mathrm{A}$ |
| Reference voltage: pin VREF |  |  |  |  |  |  |
| $\mathrm{V}_{\text {VREF }}$ | reference voltage | $\mathrm{I}_{\mathrm{L}}=10 \mu \mathrm{~A}$ | 2.86 | 2.95 | 3.04 | V |
| $\Delta \mathrm{V}_{\text {VREF }}$ | reference voltage stability | $\begin{aligned} & \mathrm{I}_{\mathrm{L}}=10 \mu \mathrm{~A} ; \\ & \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C} \end{aligned}$ | - | -0.64 | - | \% |
| $I_{\text {source }}$ | source current |  | 1 | - | - | mA |
| $\mathrm{I}_{\text {sink }}$ | sink current |  | 1 | - | - | mA |
| $\mathrm{Z}_{0}$ | output impedance | $\mathrm{L}_{\mathrm{L}}=1 \mathrm{~mA}$ source | - | 3.0 | - | $\Omega$ |
| Current supply: pin IREF |  |  |  |  |  |  |
| $V_{1}$ | input voltage |  | - | 2.5 | - | V |
| $I_{1}$ | reference input current range |  | 65 | - | 95 | $\mu \mathrm{A}$ |
| Voltage controlled oscillator |  |  |  |  |  |  |
| Output: pin CSW |  |  |  |  |  |  |
| $\mathrm{V}_{0}$ | output control voltage |  | 2.7 | 3.0 | 3.3 | V |
| $\mathrm{V}_{\text {clamp }}$ | clamp voltage | burn state | 2.8 | 3.1 | 3.4 | V |
| Voltage controlled oscillator output: pin CF |  |  |  |  |  |  |
| $\mathrm{f}_{\max }$ | maximum bridge frequency |  | 90 | 100 | 110 | kHz |
| $\mathrm{f}_{\text {min }}$ | minimum bridge frequency |  | 38.9 | 40.5 | 42.1 | kHz |
| $\Delta \mathrm{f}_{\text {stab }}$ | frequency stability | $\mathrm{T}_{\mathrm{amb}}=-20^{\circ} \mathrm{C}$ to $+80^{\circ} \mathrm{C}$ | - | 1.3 | - | \% |
| $\mathrm{t}_{\text {start }}$ | first output oscillator stroke time |  | - | 50 | - | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\text {no(min) }}$ | minimum non-overlap time | GH to GL | 0.68 | 0.90 | 1.13 | $\mu \mathrm{s}$ |
|  |  | GL to GH | 0.75 | 1.00 | 1.25 | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\text {no(max) }}$ | maximum non-overlap time | $\mathrm{f}_{\text {bridge }}=40 \mathrm{kHz}$ | [1] - | 7.5 | - | $\mu \mathrm{s}$ |
| $\mathrm{V}_{\text {CF(high) }}$ | high-level oscillator output voltage | $f=f_{\text {min }}$ | - | 2.5 | - | V |

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Table 6: Characteristics ...continued
$V_{D D}=13 \mathrm{~V} ; V_{F V D D}-V_{S H}=13 \mathrm{~V} ; T_{\text {amb }}=25^{\circ} \mathrm{C}$; all voltages referenced to GND; see test circuit of Figure 8; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{I}_{\mathrm{O} \text { (sart })}$ | oscillator output start current | $\mathrm{V}_{\mathrm{CF}}=1.5 \mathrm{~V}$ | 3.8 | 4.5 | 5.2 | $\mu \mathrm{~A}$ |
| $\mathrm{I}_{\mathrm{o}(\min )}$ | minimum oscillator output current | $\mathrm{V}_{\mathrm{CF}}=1.5 \mathrm{~V}$ | - | 21 | - | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{O}(\max )}$ | maximum oscillator output <br> current | $\mathrm{V}_{\mathrm{CF}}=1.5 \mathrm{~V}$ | - | 54 | - | $\mu \mathrm{A}$ |

Output drivers
High-side driver output: pin GH

| $\mathrm{V}_{\mathrm{OH}}$ | HIGH-level output voltage | $\mathrm{I}_{0}=10 \mathrm{~mA}$ | 12.5 | - | - | V |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{OL}}$ | LOW-level output voltage | $\mathrm{I}_{\mathrm{O}}=10 \mathrm{~mA}$ | - | - | 0.5 | V |
| $\mathrm{I}_{\mathrm{O} \text { (source) }}$ | output source current | $\mathrm{V}_{\mathrm{GH}}-\mathrm{V}_{\mathrm{SH}}=0 \mathrm{~V}$ | 135 | 180 | 235 | mA |
| $\mathrm{I}_{\mathrm{O} \text { (sink) }}$ | output sink current | $\mathrm{V}_{\mathrm{GH}}-\mathrm{V}_{\mathrm{SH}}=13 \mathrm{~V}$ | 265 | 330 | 415 | mA |
| $\mathrm{R}_{\text {on }}$ | on resistance | $\mathrm{I}_{\mathrm{O}}=10 \mathrm{~mA}$ | 32 | 39 | 45 | $\Omega$ |
| $\mathrm{R}_{\text {off }}$ | off resistance | $\mathrm{I}_{\mathrm{O}}=10 \mathrm{~mA}$ | 16 | 21 | 26 | $\Omega$ |

Low-side driver output: pin GL

| $\mathrm{V}_{\mathrm{OH}}$ | HIGH-level output voltage | $\mathrm{I}_{\mathrm{O}}=10 \mathrm{~mA}$ | 12.5 | - | - | V |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{OL}}$ | LOW-level output voltage | $\mathrm{I}_{\mathrm{O}}=10 \mathrm{~mA}$ | - | - | 0.5 | V |
| $\mathrm{I}_{\mathrm{O} \text { (source) }}$ | output source current | $\mathrm{V}_{\mathrm{GL}}=0$ | 135 | 200 | 235 | mA |
| $\mathrm{I}_{\mathrm{O} \text { (sink) }}$ | output sink current | $\mathrm{V}_{\mathrm{GL}}=13 \mathrm{~V}$ | 265 | 330 | 415 | mA |
| $\mathrm{R}_{\text {on }}$ | on resistance | $\mathrm{I}_{0}=10 \mathrm{~mA}$ | 32 | 39 | 45 | $\Omega$ |
| $\mathrm{R}_{\text {off }}$ | off resistance | $\mathrm{I}_{0}=10 \mathrm{~mA}$ | 16 | 21 | 26 | $\Omega$ |

Floating supply voltage: pin $F V_{D D}$

| $V_{\text {FVDD }}$ | lockout voltage |  | 2.8 | 3.5 | 4.2 | V |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $I_{\text {FVDD }}$ | floating well supply current | DC level at <br> $V_{G H}-V_{S H}=13 \mathrm{~V}$ | - | 35 | - | $\mu \mathrm{A}$ |
|  |  |  |  |  |  |  |

Bootstrap diode

| $V_{\text {boot }}$ | bootstrap diode forward drop <br> voltage | $\mathrm{I}=5 \mathrm{~mA}$ | 1.3 | 1.7 | 2.1 | V |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |

Preheat current sensor
Input: pin PCS

|  | input current | $\mathrm{V}_{\mathrm{PCS}}=0.6 \mathrm{~V}$ | - | - | 1 | $\mu \mathrm{~A}$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{I}_{\mathrm{i}}$ | preheat voltage |  | 0.57 | 0.60 | 0.63 | V |
| $\mathrm{~V}_{\mathrm{ph}}$ |  |  |  |  |  |  |
| Output: pin CSW | output source current | $\mathrm{V}_{\mathrm{CSW}}=2.0 \mathrm{~V}$ | 9.0 | 10 | 11 | $\mu \mathrm{~A}$ |
| $\mathrm{I}_{\mathrm{O} \text { (source) }}$ | output sink current | $\mathrm{V}_{\mathrm{CSW}}=2.0 \mathrm{~V}$ | - | 10 | - | $\mu \mathrm{A}$ |

Adaptive non-overlap and capacitive mode detection; pin ACM

| $\mathrm{I}_{\mathrm{i}}$ | input current | $\mathrm{V}_{\mathrm{ACM}}=0.6 \mathrm{~V}$ | - | - | 1 | $\mu \mathrm{~A}$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{~V}_{\mathrm{CMDP}}$ | positive capacitive mode <br> detection voltage | 80 | 100 | 120 | mV |  |
| $\mathrm{V}_{\mathrm{CMDN}}$ | negative capacitive mode <br> detection voltage | -68 | -85 | -102 | mV |  |
|  | ner |  |  |  |  |  |

Table 6: Characteristics ...continued
$V_{D D}=13 \mathrm{~V} ; V_{F V D D}-V_{S H}=13 \mathrm{~V} ; T_{\text {amb }}=25^{\circ} \mathrm{C}$; all voltages referenced to GND; see test circuit of Figure 8; unless otherwise specified.

| Symbol Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Lamp voltage sensor |  |  |  |  |  |
| Input: pin LVS |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{i}} \quad$ input current | $\mathrm{V}_{\mathrm{LVS}}=0.81 \mathrm{~V}$ | - | - | 1 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {lamp(fail) }}$ lamp fail voltage |  | 0.77 | 0.81 | 0.85 | V |
| $\mathrm{V}_{\text {lamp(fail)(hys) }}$ lamp fail hysteresis voltage |  | 119 | 144 | 169 | mV |
| $\mathrm{V}_{\text {lamp(max) }}$ maximum lamp voltage |  | 1.44 | 1.49 | 1.54 | V |
| Output: pin CSW |  |  |  |  |  |
| $\mathrm{I}_{0(\text { sink })} \quad$ output sink current | $\mathrm{V}_{\text {CSW }}=2.0 \mathrm{~V}$ | 27 | 30 | 33 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{0 \text { (source) }}$ ignition output source current | $\mathrm{V}_{\text {csw }}=2.0 \mathrm{~V}$ | 9.0 | 10 | 11 | $\mu \mathrm{A}$ |

Average current sensor
Input: pins CSP and CSN

| $\mathrm{I}_{\mathrm{i}}$ | input current | $\mathrm{V}_{\mathrm{CS}}=0 \mathrm{~V}$ | - | - | 1 | $\mu \mathrm{A}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {offset }}$ | offset voltage | $\mathrm{V}_{\text {CSP }}=\mathrm{V}_{\text {CSN }}=0 \mathrm{~V}$ to 2.5 V | -2 | 0 | +2 | mV |
| $\mathrm{gm}_{\mathrm{m}}$ | transconductance | $\mathrm{f}=1 \mathrm{kHz}$ | 1900 | 3800 | 5700 | $\mu \mathrm{A} / \mathrm{mV}$ |
| Output: pin CSW |  |  |  |  |  |  |
| $\mathrm{I}_{0}$ | output current | source and sink; $\mathrm{V}_{\mathrm{CSW}}=2 \mathrm{~V}$ | 85 | 95 | 105 | $\mu \mathrm{A}$ |
| Preheat timer; pin CT |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{ph}}$ | preheat time | $\begin{aligned} & \mathrm{C}_{\mathrm{CT}}=330 \mathrm{nF} ; \\ & \mathrm{R}_{\text {IREF }}=33 \mathrm{k} \Omega \end{aligned}$ | 1.6 | 1.8 | 2.0 | s |
| $t_{\text {ign }}$ | ignition time | $\begin{aligned} & \mathrm{C}_{\mathrm{CT}}=330 \mathrm{nF} ; \\ & \mathrm{R}_{\text {IREF }}=33 \mathrm{k} \Omega \end{aligned}$ | - | 0.32 | - | s |
| $\mathrm{I}_{0}$ | output current | $\mathrm{V}_{\text {CT }}=2.5 \mathrm{~V}$ | 5.5 | 5.9 | 6.3 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\mathrm{OL}}$ | LOW-level output voltage |  | - | 1.4 | - | V |
| $\mathrm{V}_{\mathrm{OH}}$ | HIGH-level output voltage |  | - | 3.6 | - | V |
| $\mathrm{V}_{\text {hys }}$ | output hysteresis voltage |  | 2.05 | 2.20 | 2.35 | V |

[1] The maximum non-overlap time is determined by the level of the CF signal. If this signal exceeds a level of 1.25 V , the non-overlap will end, resulting in a maximum non-overlap time of $7.5 \mu \mathrm{~s}$ at a bridge frequency of 40 kHz .


## 13. Test information

### 13.1 Quality information

The General Quality Specification for Integrated Circuits, SNW-FQ-611 is applicable.

## 14. Package outline



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | $\begin{gathered} \mathrm{A} \\ \max . \end{gathered}$ | $\mathrm{A}_{1}$ | $\mathrm{A}_{2}$ | $\mathrm{A}_{3}$ | $\mathrm{b}_{\mathrm{p}}$ | c | $D^{(1)}$ | $E^{(1)}$ | e | $\mathrm{H}_{\mathrm{E}}$ | L | $L_{p}$ | Q | v | w | y | $\mathrm{Z}^{(1)}$ | $\theta$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.75 | $\begin{aligned} & 0.25 \\ & 0.10 \\ & \hline \end{aligned}$ | $\begin{aligned} & 1.45 \\ & 1.25 \end{aligned}$ | 0.25 | $\begin{aligned} & 0.49 \\ & 0.36 \end{aligned}$ | $\begin{aligned} & 0.25 \\ & 0.19 \end{aligned}$ | $\begin{gathered} 10.0 \\ 9.8 \end{gathered}$ | $\begin{aligned} & 4.0 \\ & 3.8 \end{aligned}$ | 1.27 | $\begin{aligned} & 6.2 \\ & 5.8 \end{aligned}$ | 1.05 | $\begin{aligned} & 1.0 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & 0.7 \\ & 0.6 \end{aligned}$ | 0.25 | 0.25 | 0.1 | $\begin{aligned} & 0.7 \\ & 0.3 \\ & \hline \end{aligned}$ | $8^{\circ}$ |
| inches | 0.069 | $\begin{array}{\|l\|} \hline 0.010 \\ 0.004 \\ \hline \end{array}$ | $\begin{aligned} & 0.057 \\ & 0.049 \end{aligned}$ | 0.01 | $\begin{aligned} & 0.019 \\ & 0.014 \end{aligned}$ | $\begin{array}{\|l\|} \hline 0.0100 \\ 0.0075 \end{array}$ | $\begin{aligned} & 0.39 \\ & 0.38 \end{aligned}$ | $\begin{aligned} & 0.16 \\ & 0.15 \end{aligned}$ | 0.05 | $\begin{aligned} & 0.244 \\ & 0.228 \end{aligned}$ | 0.041 | $\begin{aligned} & 0.039 \\ & 0.016 \end{aligned}$ | $\begin{aligned} & 0.028 \\ & 0.020 \end{aligned}$ | 0.01 | 0.01 | 0.004 | $\begin{aligned} & 0.028 \\ & 0.012 \end{aligned}$ | $0^{\circ}$ |

Note

1. Plastic or metal protrusions of 0.15 mm ( 0.006 inch ) maximum per side are not included.

| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN <br> PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |  |
| SOT109-1 | $076 E 07$ | MS-012 |  |  | - |  |

Fig 9. Package outline SOT109-1 (SO16)
DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | $\begin{gathered} \mathbf{A}_{1} \\ \text { min. } \end{gathered}$ | $\begin{gathered} \mathbf{A}_{2} \\ \max . \end{gathered}$ | b | $\mathrm{b}_{1}$ | C | $D^{(1)}$ | $E^{(1)}$ | e | $e_{1}$ | L | $\mathrm{M}_{\mathrm{E}}$ | $\mathrm{M}_{\mathrm{H}}$ | w | $\mathbf{Z}^{(1)}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 4.7 | 0.51 | 3.7 | $\begin{aligned} & 1.40 \\ & 1.14 \end{aligned}$ | $\begin{aligned} & 0.53 \\ & 0.38 \end{aligned}$ | $\begin{aligned} & 0.32 \\ & 0.23 \end{aligned}$ | $\begin{aligned} & 21.8 \\ & 21.4 \end{aligned}$ | $\begin{aligned} & 6.48 \\ & 6.20 \end{aligned}$ | 2.54 | 7.62 | $\begin{aligned} & 3.9 \\ & 3.4 \end{aligned}$ | $\begin{aligned} & 8.25 \\ & 7.80 \end{aligned}$ | $\begin{aligned} & 9.5 \\ & 8.3 \end{aligned}$ | 0.254 | 2.2 |
| inches | 0.19 | 0.02 | 0.15 | $\begin{aligned} & 0.055 \\ & 0.045 \end{aligned}$ | $\begin{aligned} & 0.021 \\ & 0.015 \end{aligned}$ | $\begin{aligned} & 0.013 \\ & 0.009 \end{aligned}$ | $\begin{aligned} & 0.86 \\ & 0.84 \end{aligned}$ | $\begin{aligned} & 0.26 \\ & 0.24 \end{aligned}$ | 0.1 | 0.3 | $\begin{aligned} & 0.15 \\ & 0.13 \end{aligned}$ | $\begin{aligned} & 0.32 \\ & 0.31 \end{aligned}$ | $\begin{aligned} & 0.37 \\ & 0.33 \end{aligned}$ | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm ( 0.01 inch) maximum per side are not included.

| OUTLINE VERSION | REFERENCES |  |  | EUROPEAN PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |
| SOT38-1 | 050G09 | MO-001 | SC-503-16 | $\oplus$ | $\begin{aligned} & -99-12-27 \\ & 03-02-13 \end{aligned}$ |

Fig 10. Package outline SOT38-1 (DIP16)

## 15. Soldering

### 15.1 Introduction

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our Data Handbook IC26; Integrated Circuit Packages (document order number 9398652 90011).

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mount components are mixed on one printed-circuit board. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Driven by legislation and environmental forces the worldwide use of lead-free solder pastes is increasing.

### 15.2 Through-hole mount packages

### 15.2.1 Soldering by dipping or by solder wave

Typical dwell time of the leads in the wave ranges from 3 seconds to 4 seconds at $250^{\circ} \mathrm{C}$ or $265^{\circ} \mathrm{C}$, depending on solder material applied, SnPb or Pb-free respectively.

The total contact time of successive solder waves must not exceed 5 seconds.
The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $\mathrm{T}_{\operatorname{stg}(\max )}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

### 15.2.2 Manual soldering

Apply the soldering iron ( 24 V or less) to the lead(s) of the package, either below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than $300^{\circ} \mathrm{C}$ it may remain in contact for up to 10 seconds. If the bit temperature is between $300^{\circ} \mathrm{C}$ and $400^{\circ} \mathrm{C}$, contact may be up to 5 seconds.

### 15.3 Surface mount packages

### 15.3.1 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 seconds and 200 seconds depending on heating method.

Typical reflow peak temperatures range from $215^{\circ} \mathrm{C}$ to $270^{\circ} \mathrm{C}$ depending on solder paste material. The top-surface temperature of the packages should preferably be kept:

- below $225{ }^{\circ} \mathrm{C}$ (SnPb process) or below $245{ }^{\circ} \mathrm{C}$ (Pb-free process)
- for all BGA, HTSSON..T and SSOP..T packages
- for packages with a thickness $\geq 2.5 \mathrm{~mm}$
- for packages with a thickness $<2.5 \mathrm{~mm}$ and a volume $\geq 350 \mathrm{~mm}^{3}$ so called thick/large packages.
- below $240{ }^{\circ} \mathrm{C}$ (SnPb process) or below $260{ }^{\circ} \mathrm{C}$ (Pb-free process) for packages with a thickness < 2.5 mm and a volume $<350 \mathrm{~mm}^{3}$ so called small/thin packages.

Moisture sensitivity precautions, as indicated on packing, must be respected at all times.

### 15.3.2 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
- larger than or equal to 1.27 mm , the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
- smaller than 1.27 mm , the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.
The footprint must incorporate solder thieves at the downstream end.
- For packages with leads on four sides, the footprint must be placed at a $45^{\circ}$ angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time of the leads in the wave ranges from 3 seconds to 4 seconds at $250^{\circ} \mathrm{C}$ or $265^{\circ} \mathrm{C}$, depending on solder material applied, SnPb or Pb -free respectively.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

### 15.3.3 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage ( 24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300^{\circ} \mathrm{C}$.

When using a dedicated tool, all other leads can be soldered in one operation within 2 seconds to 5 seconds between $270^{\circ} \mathrm{C}$ and $320^{\circ} \mathrm{C}$.

### 15.4 Package related soldering information

Table 7: Suitability of IC packages for wave, reflow and dipping soldering methods

| Mounting | Package [1] | Soldering method |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Wave | Reflow [2] | Dipping |
| Through-hole mount | CPGA, HCPGA | suitable | - | - |
|  | DBS, DIP, HDIP, RDBS, SDIP, SIL | suitable [3] | - | suitable |
| Through-hole-surface mount | PMFP [4] | not suitable | not suitable | - |
| Surface mount | BGA, HTSSON..T [5], LBGA, <br> LFBGA, SQFP, SSOP..T [5], <br> TFBGA, VFBGA, XSON | not suitable | suitable | - |
|  | DHVQFN, HBCC, HBGA, HLQFP, HSO, HSOP, HSQFP, HSSON, HTQFP, HTSSOP, HVQFN, HVSON, SMS | not suitable [6] | suitable | - |
|  | PLCC []], SO, SOJ | suitable | suitable | - |
|  | LQFP, QFP, TQFP | not recommended [7] [8] | suitable | - |
|  | SSOP, TSSOP, VSO, VSSOP | not recommended [9] | suitable | - |
|  | CWQCCN..L[10], WQCCN..L[10] | not suitable | not suitable | - |

[1] For more detailed information on the BGA packages refer to the (LF)BGA Application Note (AN01026); order a copy from your Philips Semiconductors sales office.
[2] All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods.
[3] For SDIP packages, the longitudinal axis must be parallel to the transport direction of the printed-circuit board.
[4] Hot bar soldering or manual soldering is suitable for PMFP packages.
[5] These transparent plastic packages are extremely sensitive to reflow soldering conditions and must on no account be processed through more than one soldering cycle or subjected to infrared reflow soldering with peak temperature exceeding $217^{\circ} \mathrm{C} \pm 10^{\circ} \mathrm{C}$ measured in the atmosphere of the reflow oven. The package body peak temperature must be kept as low as possible.
[6] These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
[7] If wave soldering is considered, then the package must be placed at a $45^{\circ}$ angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
[8] Wave soldering is suitable for LQFP, QFP and TQFP packages with a pitch (e) larger than 0.8 mm ; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm .
[9] Wave soldering is suitable for SSOP, TSSOP, VSO and VSSOP packages with a pitch (e) equal to or larger than 0.65 mm ; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm .
[10] Image sensor packages in principle should not be soldered. They are mounted in sockets or delivered pre-mounted on flex foil. However, the image sensor package can be mounted by the client on a flex foil by using a hot bar soldering process. The appropriate soldering profile can be provided on request.

## -

600 V driver IC for HF fluorescent lamps

## 16. Revision history

Table 8: Revision history

| Document ID | Release date | Data sheet status | Change notice | Doc. number | Supersedes |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| UBA2014_2 | 20050912 | Product data sheet | - | 939775011428 | UBA2014_1 |

## 17. Data sheet status

| Level | Data sheet status [1] | Product status [2] [3] | Definition |
| :---: | :---: | :---: | :---: |
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification - The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition - Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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